Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	1781	438/478.ccls. or 438/479.ccls. or 438/482.ccls. or 438/486.ccls. or 438/488.ccls.	USPAT	OR	ON	2005/02/02 07:46
L2	394	(438/584.ccls. or 438/660.ccls. or 438/665.ccls. or 438/684.ccls. or 438/795.ccls. or 438/799.ccls.) and (polycrystalline with silicon)	USPAT	OR	ON	2005/02/02 07:54
L3	26	L2 and (silicon adj grain)	USPAT	OR	ON	2005/02/02 07:54
L4	4	(("20040201023") or ("20040058076") or ("20040055999") or ("20040038438")).PN.	US-PGPUB	OR'	OFF	2005/02/02 08:38
L5	2	(("6677222") or ("6593215")).PN.	USPAT	OR	OFF	2005/02/02 08:38
S2	5066	polycrystalline and silicon and (TFT or (thin adj film)) and (protrusion or bump or hillock or garin or boundary or hill or spike)	USPAT	OR	ON	2005/02/01 16:10
S3	7709	polycrystalline and silicon and (TFT or (thin adj film)) and (protrusion or bump or hillock or garin or boundary or hill or spike)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/01 16:13
S4	5413	S3 and (polycrystalline with silicon)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/01 16:21
S5	682	S4 and (anneal\$3 with excimer)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/02 08:36
S6	394	(438/584.ccls. or 438/660.ccls. or 438/665.ccls. or 438/684.ccls. or 438/795.ccls. or 438/799.ccls.) and (polycrystalline with silicon)	USPAT	OR	ON	2005/02/01 17:00
58	274	S6 and ((silicon adj grain) or crystallization or annealing)	USPAT	OR	ON	2005/02/01 17:01